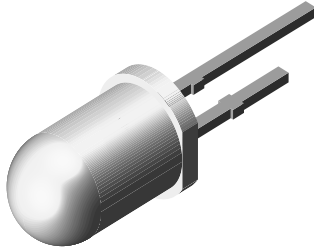




Infrared Emitting Diode, 950 nm, GaAs



94 8390

DESCRIPTION

TSUS5400 is an infrared, 950 nm emitting diode in GaAs technology molded in a blue-gray tinted plastic package.

FEATURES

- Package type: leaded
- Package form: T-1 $\frac{3}{4}$
- Dimensions (in mm): \varnothing 5
- Leads with stand-off
- Peak wavelength: $\lambda_p = 950$ nm
- High reliability
- Angle of half intensity: $\varphi = \pm 22^\circ$
- Low forward voltage
- Suitable for high pulse current operation
- Good spectral matching with Si photodetectors
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC



Note

** Please see document "Vishay Material Category Policy": www.vishay.com/doc?99902

APPLICATIONS

- Infrared remote control and free air transmission systems with low forward voltage and small package requirements
- Emitter in transmissive sensors
- Emitter in reflective sensors

| PRODUCT SUMMARY | | | | |
|-----------------|---------------|-----------------|------------------|------------|
| COMPONENT | I_e (mW/sr) | φ (deg) | λ_p (nm) | t_r (ns) |
| TSUS5400 | 14 | ± 22 | 950 | 800 |
| TSUS5401 | 17 | ± 22 | 950 | 800 |
| TSUS5402 | 20 | ± 22 | 950 | 800 |

Note

- Test conditions see table "Basic Characteristics"

| ORDERING INFORMATION | | | |
|----------------------|-----------|------------------------------|-------------------|
| ORDERING CODE | PACKAGING | REMARKS | PACKAGE FORM |
| TSUS5400 | Bulk | MOQ: 4000 pcs, 4000 pcs/bulk | T-1 $\frac{3}{4}$ |
| TSUS5401 | Bulk | MOQ: 4000 pcs, 4000 pcs/bulk | T-1 $\frac{3}{4}$ |
| TSUS5402 | Bulk | MOQ: 4000 pcs, 4000 pcs/bulk | T-1 $\frac{3}{4}$ |

Note

- MOQ: minimum order quantity

| ABSOLUTE MAXIMUM RATINGS ($T_{amb} = 25^\circ\text{C}$, unless otherwise specified) | | | | |
|---|--|------------|---------------|------------------|
| PARAMETER | TEST CONDITION | SYMBOL | VALUE | UNIT |
| Reverse voltage | | V_R | 5 | V |
| Forward current | | I_F | 150 | mA |
| Peak forward current | $t_p/T = 0.5, t_p = 100 \mu\text{s}$ | I_{FM} | 300 | mA |
| Surge forward current | $t_p = 100 \mu\text{s}$ | I_{FSM} | 2.5 | A |
| Power dissipation | | P_V | 170 | mW |
| Junction temperature | | T_j | 100 | $^\circ\text{C}$ |
| Operating temperature range | | T_{amb} | - 40 to + 85 | $^\circ\text{C}$ |
| Storage temperature range | | T_{stg} | - 40 to + 100 | $^\circ\text{C}$ |
| Soldering temperature | $t \leq 5$ s, 2 mm from case | T_{sd} | 260 | $^\circ\text{C}$ |
| Thermal resistance junction/ambient | J-STD-051, leads 7 mm, soldered on PCB | R_{thJA} | 230 | K/W |

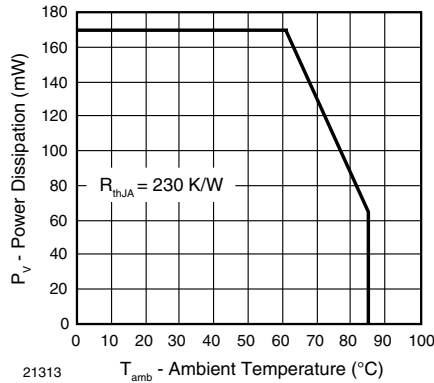


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

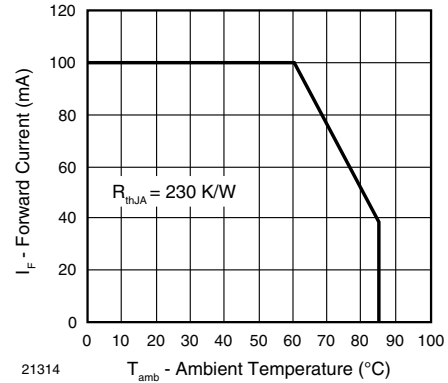


Fig. 2 - Forward Current Limit vs. Ambient Temperature

| BASIC CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified) | | | | | | |
|---|---|------------------|------|----------|------|---------------|
| PARAMETER | TEST CONDITION | SYMBOL | MIN. | TYP. | MAX. | UNIT |
| Forward voltage | $I_F = 100\text{ mA}$, $t_p = 20\text{ ms}$ | V_F | | 1.3 | 1.7 | V |
| Temperature coefficient of V_F | $I_F = 100\text{ mA}$ | TK_{V_F} | | -1.3 | | mV/K |
| Reverse current | $V_R = 5\text{ V}$ | I_R | | | 100 | μA |
| Junction capacitance | $V_R = 0\text{ V}$, $f = 1\text{ MHz}$, $E = 0$ | C_j | | 30 | | pF |
| Temperature coefficient of ϕ_e | $I_F = 20\text{ mA}$ | TK_{ϕ_e} | | -0.8 | | %/K |
| Angle of half intensity | | ϕ | | ± 22 | | deg |
| Peak wavelength | $I_F = 100\text{ mA}$ | λ_p | | 950 | | nm |
| Spectral bandwidth | $I_F = 100\text{ mA}$ | $\Delta\lambda$ | | 50 | | nm |
| Temperature coefficient of λ_p | $I_F = 100\text{ mA}$ | TK_{λ_p} | | 0.2 | | nm/K |
| Rise time | $I_F = 100\text{ mA}$ | t_r | | 800 | | ns |
| | $I_F = 1.5\text{ A}$ | t_r | | 400 | | ns |
| Fall time | $I_F = 100\text{ mA}$ | t_f | | 800 | | ns |
| | $I_F = 1.5\text{ A}$ | t_f | | 400 | | ns |
| Virtual source diameter | | d | | 2.9 | | mm |

| TYPE DEDICATED CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified) | | | | | | | |
|--|---|----------|----------|------|------|------|-------|
| PARAMETER | TEST CONDITION | PART | SYMBOL | MIN. | TYP. | MAX. | UNIT |
| Forward voltage | $I_F = 1.5\text{ A}$, $t_p = 100\text{ }\mu\text{s}$ | TSUS5400 | V_F | | 2.2 | 3.4 | V |
| | | TSUS5401 | V_F | | 2.2 | 3.4 | V |
| | | TSUS5402 | V_F | | 2.2 | 2.7 | V |
| Radiant intensity | $I_F = 100\text{ mA}$, $t_p = 20\text{ ms}$ | TSUS5400 | I_e | 7 | 14 | 35 | mW/sr |
| | | TSUS5401 | I_e | 10 | 17 | 35 | mW/sr |
| | | TSUS5402 | I_e | 15 | 20 | 35 | mW/sr |
| | $I_F = 1.5\text{ A}$, $t_p = 100\text{ }\mu\text{s}$ | TSUS5400 | I_e | 60 | 140 | | mW/sr |
| | | TSUS5401 | I_e | 85 | 160 | | mW/sr |
| | | TSUS5402 | I_e | 120 | 190 | | mW/sr |
| Radiant power | $I_F = 100\text{ mA}$, $t_p = 20\text{ ms}$ | TSUS5400 | ϕ_e | | 13 | | mW |
| | | TSUS5401 | ϕ_e | | 14 | | mW |
| | | TSUS5402 | ϕ_e | | 15 | | mW |



BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

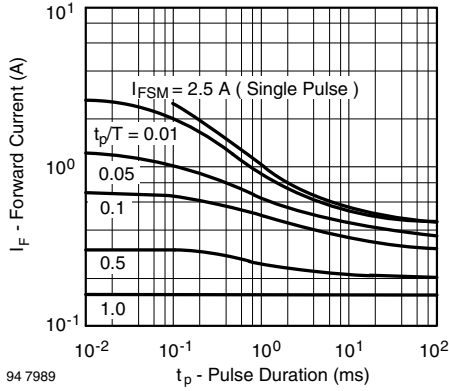


Fig. 3 - Pulse Forward Current vs. Pulse Duration

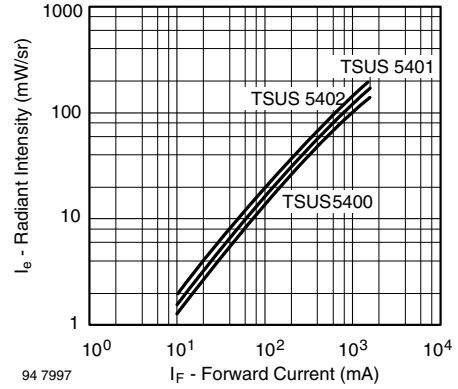


Fig. 6 - Radiant Intensity vs. Forward Current

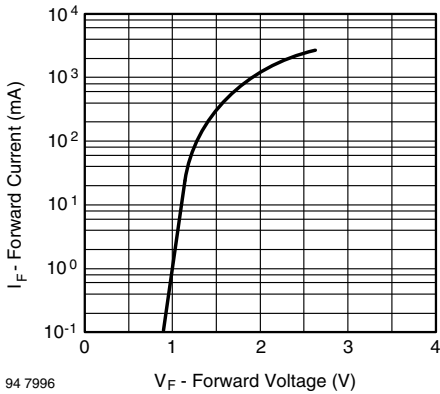


Fig. 4 - Forward Current vs. Forward Voltage

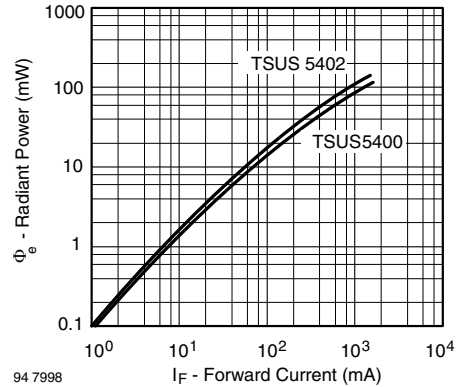


Fig. 7 - Radiant Power vs. Forward Current

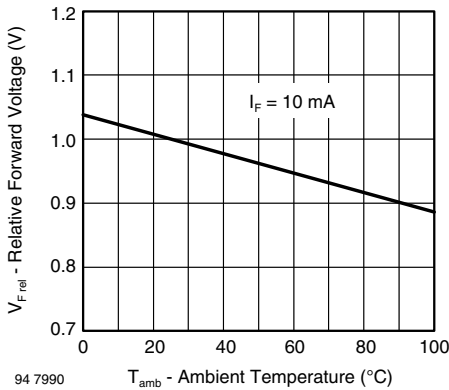


Fig. 5 - Relative Forward Voltage vs. Ambient Temperature

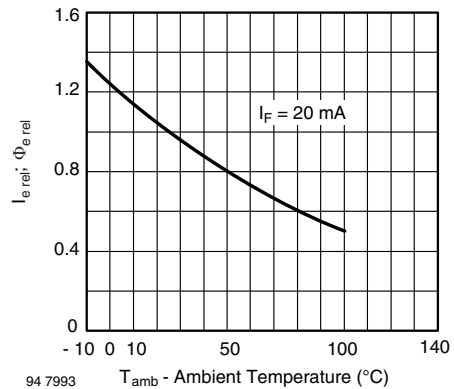


Fig. 8 - Relative Radiant Intensity/Power vs. Ambient Temperature

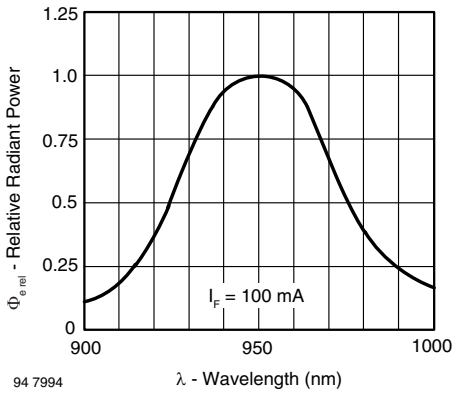


Fig. 9 - Relative Radiant Power vs. Wavelength

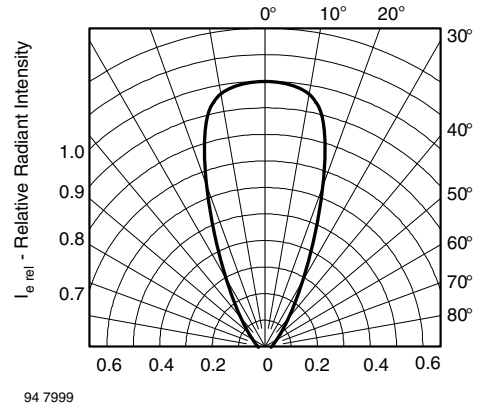
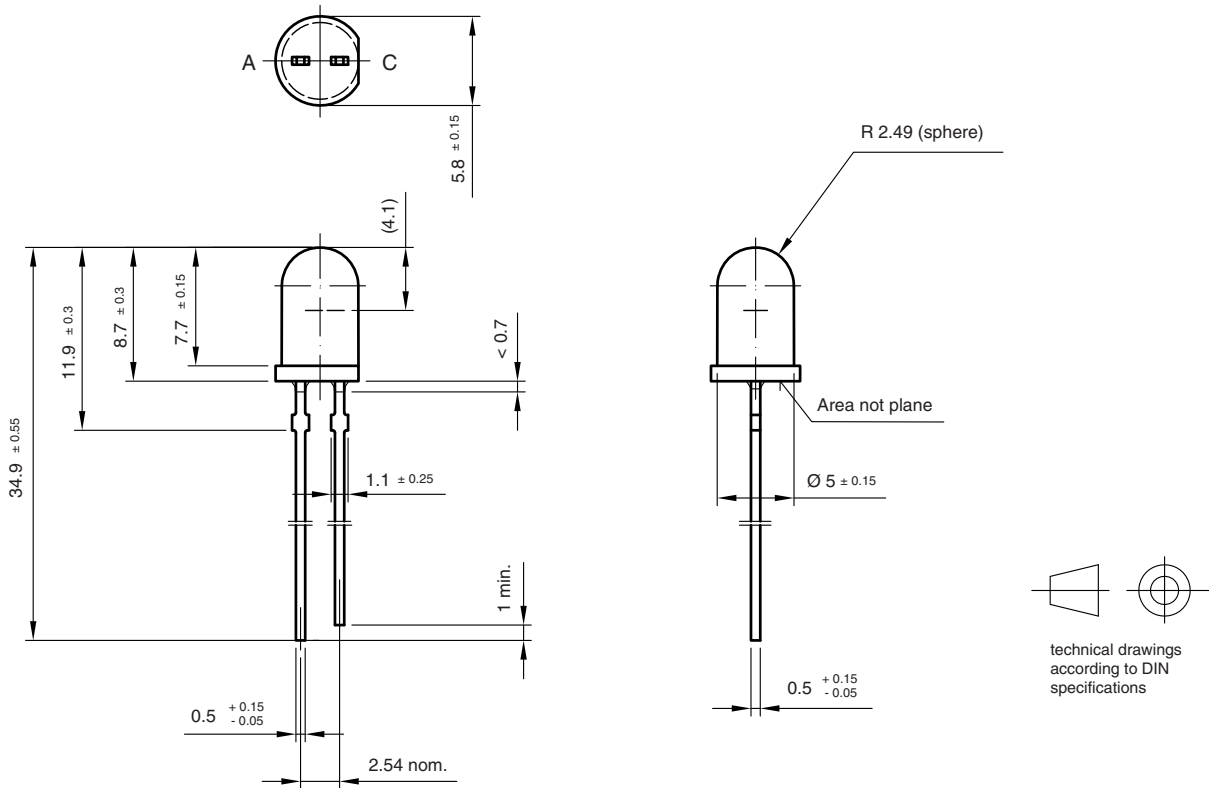


Fig. 10 - Relative Radiant Intensity vs. Angular Displacement

PACKAGE DIMENSIONS in millimeters



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 Issue: 5; 19.05.09
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